



STK28N3LLH5

N-channel 30 V, 0.0035 Ω , 28 A, PolarPAK[®]
STripFET[™]V Power MOSFET

Preliminary Data

Features

| Type | V _{DSS} | R _{DS(on)} max | R _{DS(on)} *Q _g |
|-------------|------------------|----------------------------|-------------------------------------|
| STK28N3LLH5 | 30 V | < 0.0045 Ω | 68.4 nC*m Ω |

- Ultra low top and bottom junction to case thermal resistance
- R_{DS(on)} * Q_g industry benchmark
- Extremely low on-resistance R_{DS(on)}
- Very low switching gate charge
- Fully encapsulated die
- 100% matte tin finish (in compliance with the 2002/95/EC european directive)
- High avalanche ruggedness
- PolarPAK[®] is a trademark of VISHAY

Application

- Switching applications

Description

This product utilizes the 5th generation of design rules of ST's proprietary STripFET[™] technology. The lowest available R_{DS(on)} * Q_g in this chip scale package, makes this device suitable for the most demanding DC-DC converter applications, where high power density is to be achieved.

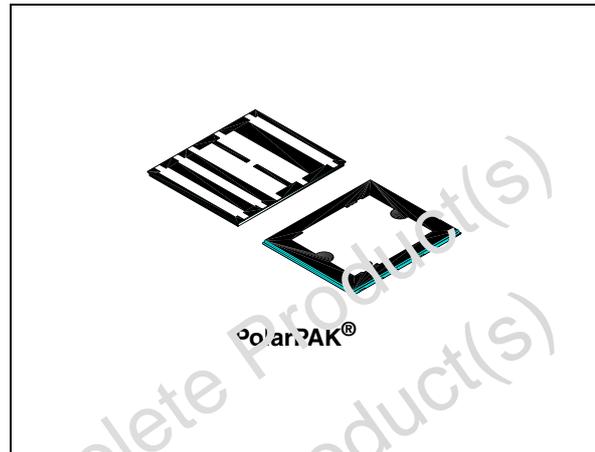


Figure 1. Internal schematic diagram

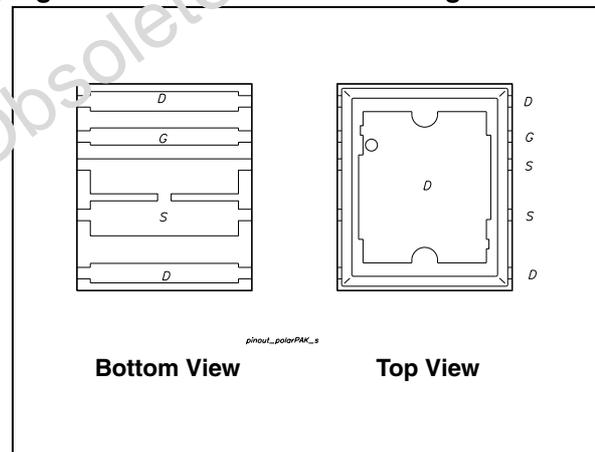


Table 1. Device summary

| Order code | Marking | Package | Packaging |
|-------------|---------|-----------------------|---------------|
| STK28N3LLH5 | 283L5 | PolarPAK [®] | Tape and reel |

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1 Electrical ratings

Table 2. Absolute maximum ratings

| Symbol | Parameter | Value | Unit |
|--------------------|---|------------|---------------------|
| V_{DS} | Drain-source voltage ($V_{GS} = 0$) | 30 | V |
| V_{GS} | Gate-source voltage | ± 22 | V |
| $I_D^{(1)}$ | Drain current (continuous) at $T_C = 25^\circ\text{C}$ | 28 | A |
| I_D | Drain current (continuous) at $T_C = 100^\circ\text{C}$ | 17.5 | A |
| $I_{DM}^{(2)}$ | Drain current (pulsed) | 112 | A |
| $P_{TOT}^{(1)}$ | Total dissipation at $T_C = 25^\circ\text{C}$ | 5.2 | W |
| | Derating factor | 0.0416 | W/ $^\circ\text{C}$ |
| $E_{AS}^{(3)}$ | Single pulse avalanche energy | 1 | J |
| T_j T_{stg} | Operating junction temperature Storage temperature | -55 to 150 | $^\circ\text{C}$ |

1. When mounted on FR-4 board of 1inch², 2 oz Cu and $\leq 10\mu\text{sec}$
2. Pulse width limited by package
3. Starting $T_j = 25^\circ\text{C}$, $I_D = 10\text{A}$, $V_{DD} = 25\text{V}$

Table 3. Thermal data

| Symbol | Parameter | Typ. | Max. | Unit |
|---------------------|--|------|------|---------------------------|
| $R_{thj-amb}^{(1)}$ | Thermal resistance junction-amb | 20 | 24 | $^\circ\text{C}/\text{W}$ |
| $R_{thj-c}^{(2)}$ | Thermal resistance junction-case (top drain) | 1 | 1.2 | $^\circ\text{C}/\text{W}$ |
| $R_{thj-c}^{(3)}$ | Thermal resistance junction-case (source) | 2.8 | 3.4 | $^\circ\text{C}/\text{W}$ |

1. When mounted on FR-4 board of 1inch², 2 oz Cu and $\leq 10\text{sec}$
2. Steady state
3. Measured at source pin when the device is mounted on FR-4 board in steady state

2 Electrical characteristics

($T_{CASE}=25^{\circ}C$ unless otherwise specified)

Table 4. On/off states

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|---------------|--|---|------|------------------|------------------|----------------------|
| $V_{(BR)DSS}$ | Drain-source breakdown voltage | $I_D = 250 \mu A, V_{GS} = 0$ | 30 | | | V |
| I_{DSS} | Zero gate voltage drain current ($V_{GS} = 0$) | $V_{DS} = \text{Max rating},$ $V_{DS} = \text{Max rating}, T_c = 125^{\circ}C$ | | | 1 10 | μA μA |
| I_{GSS} | Gate body leakage current ($V_{DS} = 0$) | $V_{GS} = \pm 22 V$ | | | 100 | nA |
| $V_{GS(th)}$ | Gate threshold voltage | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | 1 | | 2.5 | V |
| $R_{DS(on)}$ | Static drain-source on resistance | $V_{GS} = 10 V, I_D = 14 A$ $V_{GS} = 4.5 V, I_D = 14 A$ | | 0.0035 0.0047 | 0.0045 0.0055 | Ω Ω |

Table 5. Dynamic

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------|-------------------------------------|---|------|------|------|----------|
| C_{iss} | Input capacitance | | | 2300 | | pF |
| C_{oss} | Output capacitance | $V_{DS} = 25 V, f = 1 \text{ MHz}, V_{GS} = 0$ | | 450 | | pF |
| C_{rss} | Reverse transfer capacitance | | | 61 | | pF |
| Q_g | Total gate charge | $V_{DD} = 15 V, I_D = 28 A$ | | 19 | | nC |
| Q_{gs} | Gate-source charge | $V_{GS} = 4.5 V$ | | TBD | | nC |
| Q_{gd} | Gate-drain charge | (see Figure 3) | | TBD | | nC |
| Q_{gs1} | Pre V_{th} gate-to-source charge | $V_{DD} = 15 V, I_D = 28 A$ $V_{GS} = 4.5 V$ | | TBD | | nC |
| Q_{gs2} | Post V_{th} gate-to-source charge | (see Figure 8) | | TBD | | nC |
| R_G | Gate input resistance | $f = 1 \text{ MHz}$ Gate DC Bias = 0 Test signal level = 20 mV open drain | | TBD | | Ω |

Table 6. Switching times

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------------|----------------------------------|--|------|------------|------|----------|
| $t_{d(on)}$ t_r | Turn-on delay time Rise time | $V_{DD}=15\text{ V}$, $I_D=14\text{ A}$, $R_G=4.7\ \Omega$, $V_{GS}=4.5\text{ V}$ <i>(see Figure 2)</i> | | TBD TBD | | ns ns |
| $t_{d(off)}$ t_f | Turn-off delay time Fall time | $V_{DD}=15\text{ V}$, $I_D=14\text{ A}$, $R_G=4.7\ \Omega$, $V_{GS}=4.5\text{ V}$ <i>(see Figure 2)</i> | | TBD TBD | | ns ns |

Table 7. Source drain diode

| Symbol | Parameter | Test conditions | Min. | Typ. | Max. | Unit |
|-----------------------------------|--|--|------|-------------------|-----------|---------------|
| I_{SD} $I_{SDM}^{(1)}$ | Source-drain current Source-drain current (pulsed) | | | | 28 112 | A A |
| $V_{SD}^{(2)}$ | Forward on Voltage | $I_{SD}=25\text{ A}$, $V_{GS}=0$ | | | 1.1 | V |
| t_{rr} Q_{rr} I_{RRM} | Reverse recovery time Reverse recovery charge Reverse recovery current | $I_{SD}=25\text{ A}$, $di/dt = 100\text{ A}/\mu\text{s}$, $V_{DD}=20\text{ V}$, $T_j=150^\circ\text{C}$ <i>(see Figure 7)</i> | | TBD TBD TBD | | ns nC A |

1. Pulse width limited by package
2. Pulsed: pulse duration = 300 μs , duty cycle 1.5%

3 Test circuits

Figure 2. Switching times test circuit for resistive load

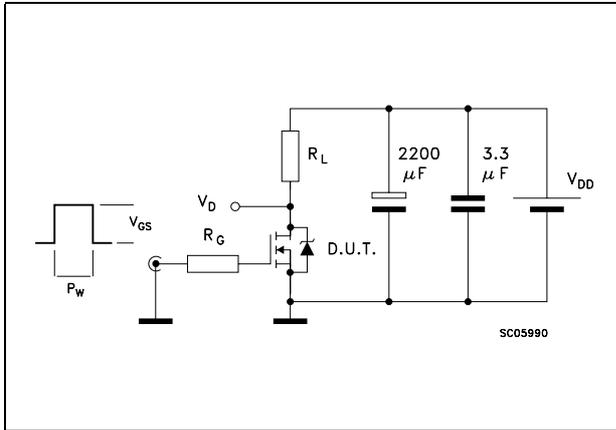


Figure 3. Gate charge test circuit

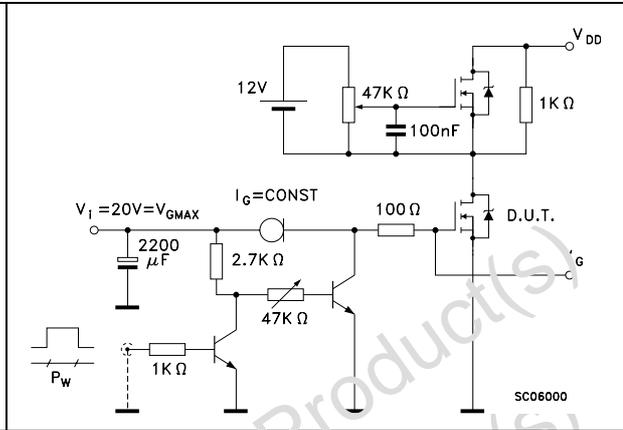


Figure 4. Test circuit for inductive load switching and diode recovery times

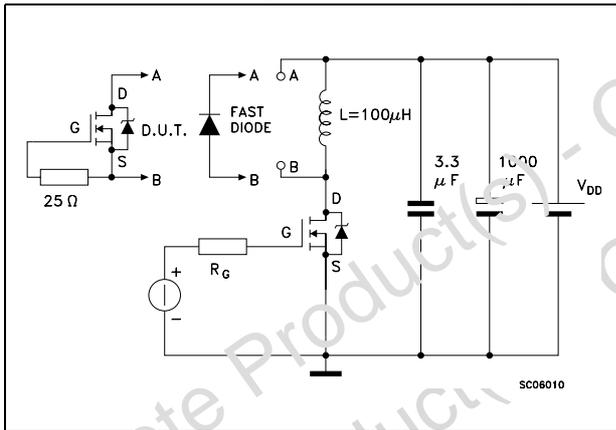


Figure 5. Unclamped inductive load test circuit

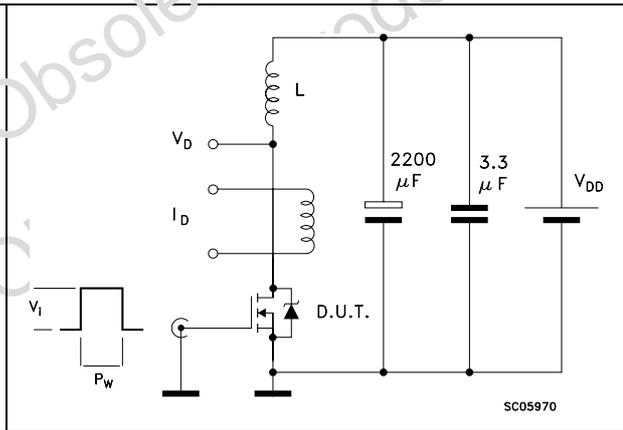


Figure 6. Unclamped inductive waveform

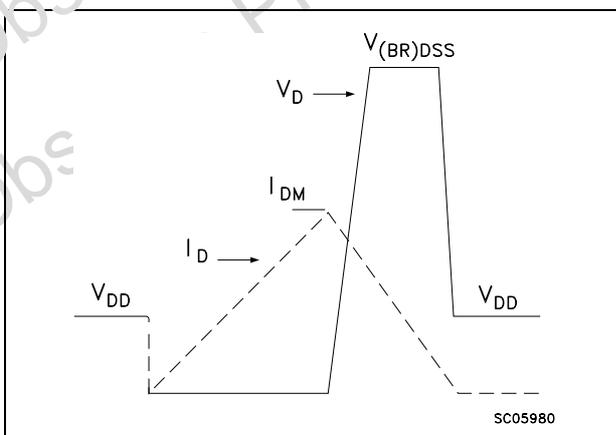


Figure 7. Switching time waveform

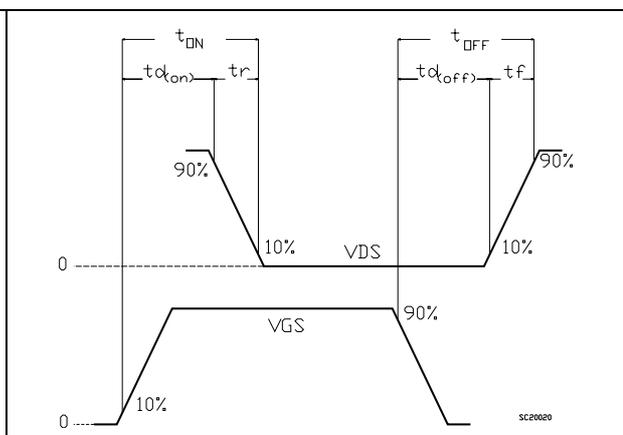
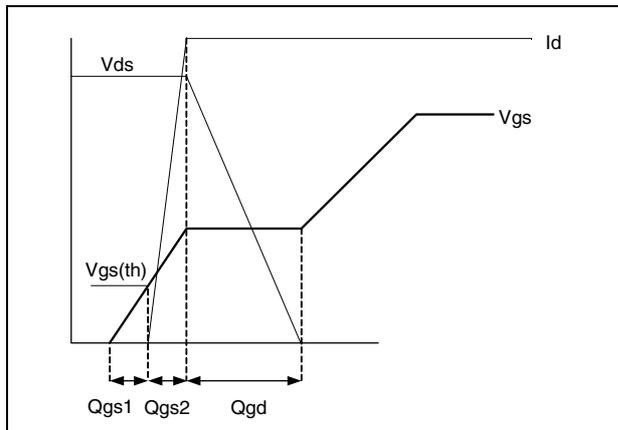


Figure 8. Gate charge waveform



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4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

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Table 8. PolarPAK® (option "S") mechanical data

| Ref. | mm | | | inch | | |
|------|------|------|------|-------|-------|-------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 0.75 | 0.80 | 0.85 | 0.030 | 0.031 | 0.033 |
| A1 | | | 0.05 | | | 0.002 |
| b1 | 0.48 | 0.58 | 0.68 | 0.019 | 0.023 | 0.027 |
| b2 | 0.41 | 0.51 | 0.61 | 0.016 | 0.020 | 0.024 |
| b3 | 2.19 | 2.29 | 2.39 | 0.086 | 0.090 | 0.094 |
| b4 | 0.89 | 1.04 | 1.19 | 0.035 | 0.041 | 0.047 |
| b5 | 0.23 | 0.33 | 0.43 | 0.009 | 0.013 | 0.017 |
| c | 0.20 | 0.25 | 0.30 | 0.008 | 0.010 | 0.012 |
| D | 6 | 6.15 | 6.30 | 0.236 | 0.242 | 0.248 |
| D1 | 5.74 | 5.89 | 6.04 | 0.226 | 0.232 | 0.238 |
| E | 5.01 | 5.16 | 5.31 | 0.197 | 0.203 | 0.209 |
| E1 | 4.75 | 4.90 | 5.05 | 0.187 | 0.193 | 0.199 |
| H1 | 0.23 | | | 0.009 | | |
| H2 | 0.45 | | 0.56 | 0.018 | | 0.022 |
| H3 | 0.31 | 0.41 | 0.51 | 0.012 | 0.016 | 0.020 |
| H4 | 0.45 | | 0.56 | 0.018 | | 0.022 |
| I1 | 1.92 | 1.97 | 2.02 | 0.075 | 0.077 | 0.079 |
| J1 | 0.38 | 0.43 | 0.48 | 0.014 | 0.016 | 0.018 |
| K1 | 4.22 | 4.37 | 4.52 | 0.166 | 0.172 | 0.178 |
| K4 | 0.24 | | | 0.009 | | |
| M1 | 4.30 | 4.50 | 4.70 | 0.169 | 0.177 | 0.185 |
| M2 | 3.43 | 3.58 | 3.73 | 0.135 | 0.141 | 0.147 |
| M3 | 0.22 | | | 0.009 | | |
| M4 | 0.05 | | | 0.002 | | |
| P1 | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 |
| T1 | 3.48 | 3.64 | 4.10 | 0.137 | 0.143 | 0.161 |
| T2 | 0.56 | 0.76 | 0.95 | 0.022 | 0.030 | 0.037 |
| T3 | 1.20 | | | 0.047 | | |
| T4 | 3.90 | | | 0.154 | | |
| T5 | | 0.18 | 0.36 | | 0.007 | 0.014 |
| < | 0° | 10° | 12° | 0° | 10° | 12° |

Figure 9. PolarPAK® (option “S”) drawings

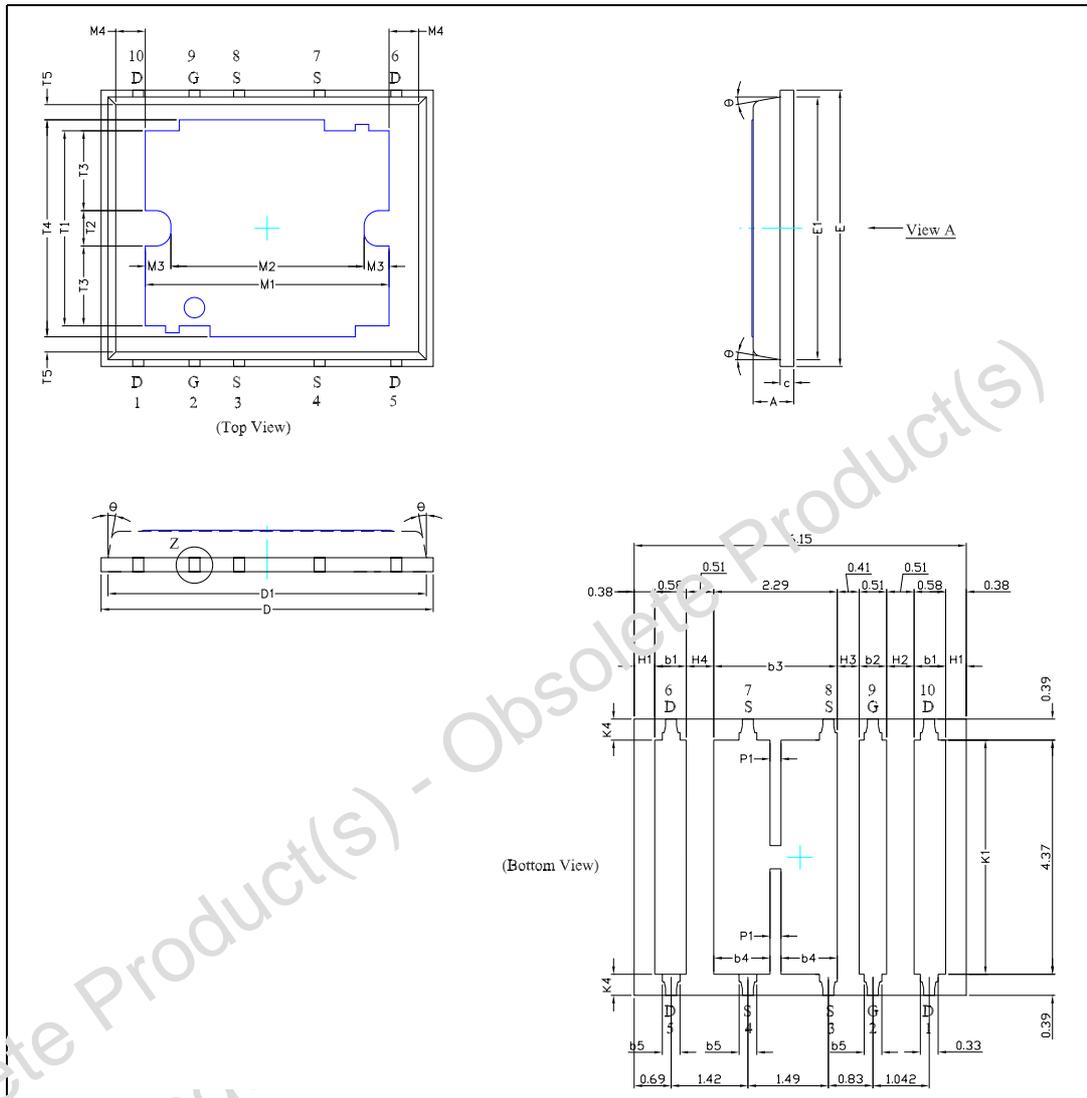
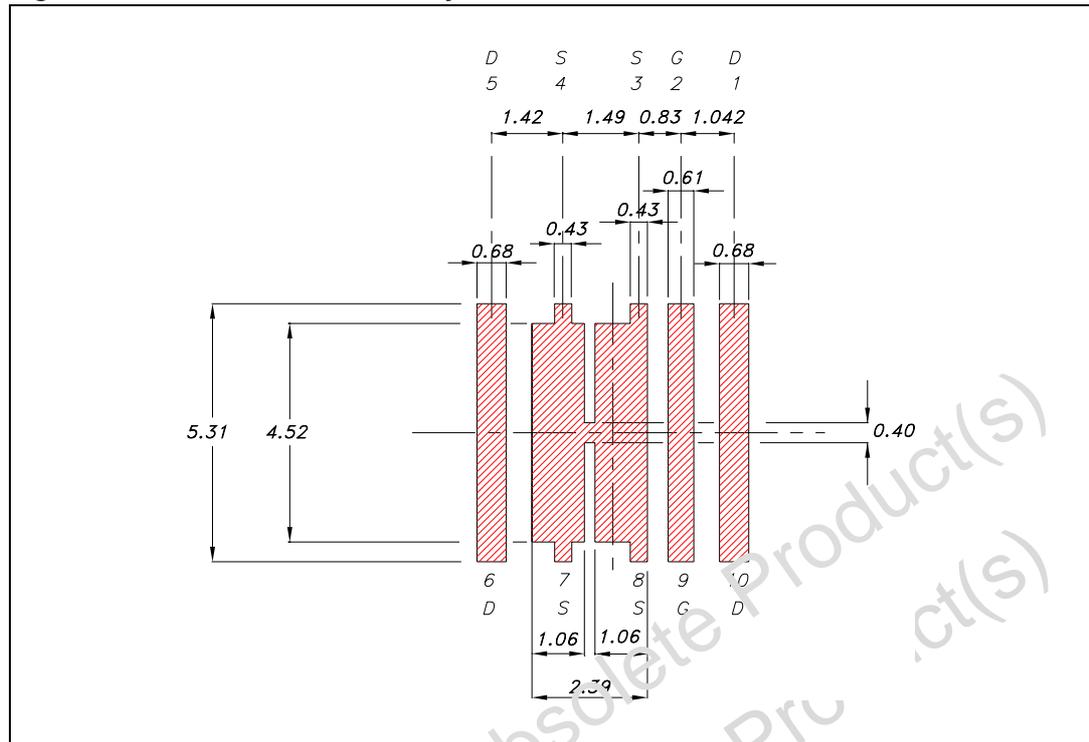


Figure 10. Recommended PAD layout



5 Revision history

Table 9. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 07-Jul-2008 | 1 | First release |
| 03-Sep-2008 | 2 | $R_{DS(on)}$ value updated. V_{GS} value updated in Table 2 and Table 4 |

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